NSN 5961-01-361-1560

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-361-1560 **Inclosure Material:** Metal **Overall Length:** Between 0.080 inches and 0.105 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.219 inches **Function For Which Designed:** Voltage reference Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-46 **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.2 regulator voltage **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current preset and 50.00 milliamperes forward current, average peak **Power Rating Per Characteristic:** 100.00 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: